LME49870 44V Single High Performance, High Fidelity Audio Operational

Amplifier



Literature Number: SNAS413B

ME49870 44V Single High Performance, High Fidelity Audio Operational Amplifier

LME49870 44V Single High Performance, High Fidelity Audio **Operational Amplifier**

General Description

National Semiconductor

The LME49870 is part of the ultra-low distortion, low noise. high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49870 audio operational amplifier delivers superior audio signal amplification for outstanding audio performance. The LME49870 combines extremely low voltage noise density (2.7nV/VHz) with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49870 has a high slew rate of ±20V/µs and an output current capability of ±26mA. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49870's outstanding CMRR (120dB), PSRR (120dB), and V_{OS} (0.1mV) give the amplifier excellent operational amplifier DC performance.

The LME49870 has a wide supply range of ±2.5V to ±22V. Over this supply range the LME49870 maintains excellent common-mode rejection, power supply rejection, and low input bias current. The LME49870 is unity gain stable. This Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49870 is available in 8-lead narrow body SOIC. Demonstration boards are available for each package.

Key Specifications

- Power Supply Voltage Range
- THD+N $(A_V = 1, V_{OUT} = 3V_{BMS}, f_{IN} = 1 \text{ kHz})$

Typical Application

Passively Equalized	RIAA Phono Preamplifier

300194k5

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$R_L = 2k\Omega$	0.00003% (typ)
$R_L = 600\Omega$	0.00003% (typ)
Input Noise Density	2.7nV/ $\sqrt{\text{Hz}}$ (typ)
Slew Rate	±20V/µs (typ)
Gain Bandwidth Product	55MHz (typ)
Open Loop Gain (R _L = 600Ω)	140dB (typ)
Input Bias Current	10nA (typ)
Input Offset Voltage	0.1mV (typ)

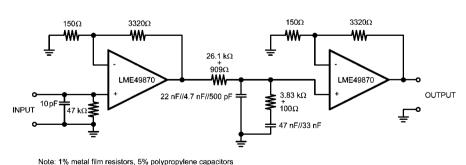
0.000009% DC Gain Linearity Error

Features

- Easily drives 600Ω loads
- Optimized for superior audio signal fidelity
- Output short circuit protection
- PSRR and CMRR exceed 120dB (typ)

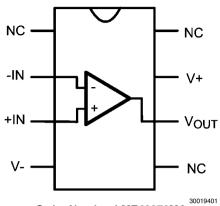
Applications

- High quality audio amplification
- High fidelity preamplifiers, phono preamps, and multimedia
- High performance professional audio
- High fidelity equalization and crossover networks with active filters
- High performance line drivers and receivers
- Low noise industrial applications including test, measurement, and ultrasound

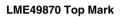


±2.5V to ±22V

Connection Diagrams



Order Number LME49870MA See NS Package Number — M08A





N — National Logo Z — Assembly Plant code X — 1 Digit Date code TT — Die Traceability L49870 — LME49870 MA — Package code

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Power Supply Voltage	
$(V_{S} = V^{+} - V^{-})$	46V
Storage Temperature	–65°C to 150°C
Input Voltage	(V-) - 0.7V to (V+) + 0.7V
Output Short Circuit (Note 3)	Continuous
Power Dissipation	Internally Limited
ESD Rating (Note 4)	2000V
ESD Rating (Note 5)	

Pins 1, 4, 7 and 8	200V
Pins 2, 3, 5 and 6	100V
Junction Temperature	150°C
Thermal Resistance	
θ _{JA} (SO)	145°C/W

Operating Ratings

Temperature Range

$T_{MIN} \le T_A \le T_{MAX}$	
Supply Voltage Range	:

 $-40^{\circ}C \le T_A \le 85^{\circ}C$ $\pm 2.5V \le V_S \le \pm 22V$

Electrical Characteristics for the LME49870 (Note 1) The following specifications apply for $V_s = \pm 18V$ and $\pm 22V$, $R_L = 2k\Omega$, $R_{SOURCE} = 10\Omega$, $f_{IN} = 1$ kHz, $T_A = 25^{\circ}$ C, unless otherwise specified.

			LME49870		
Symbol	Parameter	Conditions	Typical	Limit	Units
			(Note 6)	(Note 7)	(Limits)
THD+N	Total Harmonic Distortion + Noise	$A_{V} = 1, V_{OUT} = 3V_{rms}$ $R_{L} = 2k\Omega$ $R_{L} = 600\Omega$	0.00003 0.00003	0.00009	% (max)
IMD	Intermodulation Distortion	A _V = 1, V _{OUT} = 3V _{RMS} Two-tone, 60Hz & 7kHz 4:1	0.00005		%
GBWP	Gain Bandwidth Product		55	45	MHz (min)
SR	Slew Rate		±20	±15	V/µs (min)
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}$, -3dB referenced to output magnitude at f = 1kHz	10		MHz
t _s	Settling time	$A_V = -1$, 10V step, $C_L = 100 pF$ 0.1% error range	1.2		μs
_	Equivalent Input Noise Voltage	f _{BW} = 20Hz to 20kHz	0.34	0.65	μV _{RMS} (max)
e _n	Equivalent Input Noise Density	f = 1kHz f = 10Hz	2.5 6.4	4.7	nV/√Hz (max)
i _n	Current Noise Density	f = 1kHz f = 10Hz	1.6 3.1		pA/√Hz
M	Offset Voltage	V _S = ±18V	±0.12		mV (max)
V _{OS}		$V_{S} = \pm 22V$	±0.14	±0.7	mV (max)
ΔV _{OS} /ΔTemp	Average Input Offset Voltage Drift vs Temperature	–40°C ≤ T _A ≤ 85°C	0.1		μV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$V_{S} = \pm 18V, \Delta V_{S} = 24V$ (Note 8) $V_{S} = \pm 22V, \Delta V_{S} = 30V$	120 120	110	dB (min)
I _B	Input Bias Current	V _{CM} = 0V	10	72	nA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$	0.2		nA/°C
I _{os}	Input Offset Current	$V_{CM} = 0V$	11	65	nA (max)
		$V_{S} = \pm 18V$	+17.1 -16.9		V (min) V (min)
V _{IN-CM}	Common-Mode Input Voltage Range	$V_{\rm S} = \pm 22V$	+21.0 -20.8	(V+) - 2.0 (V-) + 2.0	V (min) V (min)

			LME4	LME49870		
Symbol	Parameter	Conditions	Typical	Limit	Units	
-			(Note 6)	(Note 7)	– (Limits)	
		V _S = ±18V	400			
		–12V≤Vcm≤12V	120		dB (min	
CMRR	Common-Mode Rejection	V _S = ±22V	100	110	I.D. (
		–15V≤Vcm≤15V	120	110	dB (min	
7	Differential Input Impedance		30		kΩ	
Z _{IN}	Common Mode Input Impedance	-10V <vcm<10v< td=""><td>1000</td><td></td><td>MΩ</td></vcm<10v<>	1000		MΩ	
		V _S = ±18V				
		–12V≤Vout≤12V				
		R _L = 600Ω	140		dB	
		$R_L = 2k\Omega$	140		dB	
		$R_L = 10\Omega$	140		dB	
A _{VOL}	Open Loop Voltage Gain	$V_{\rm S} = \pm 22V$				
		–15V≤Vout≤15V				
		R _L = 600Ω	140	125	dB	
		$R_L = 2k\Omega$	140		dB	
		R _L = 10Ω	140		dB	
		R _I = 600Ω				
		$V_{\rm S} = \pm 18 V$	±16.7		V (min	
		$V_{\rm S} = \pm 22 V$	±20.4	±19.0	V (min	
		$R_{L} = 2k\Omega$				
V _{OUTMAX}	Maximum Output Voltage Swing	$V_{\rm S}^{-} = \pm 18 V$	±17.0		V (min	
		$V_{\rm S} = \pm 22V$	±21.0		V (min	
		$R_L = 10k\Omega$				
		$V_{\rm S} = \pm 18 V$	±17.1		V (min	
		$V_{\rm S} = \pm 22V$	±21.0		V (min	
		R _L = 600Ω				
I _{OUT}	Output Current	$V_{\rm S} = \pm 20 V$	±31		mA (mir	
		V _S = ±22V	±37	±30	mA (mii	
I _{OUT-CC}	Instantaneous Short Circuit Current		+53		mA	
·001-CC			-42			
-	Output Impedance	f _{IN} = 10kHz				
R _{OUT}		Closed-Loop	0.01		Ω	
0		Open-Loop	13			
C _{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%	
I _S	Total Quiescent Current	I _{OUT} = 0mA	5	6.5	mA (ma	

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in *Absolute Maximum Ratings*, whichever is lower.

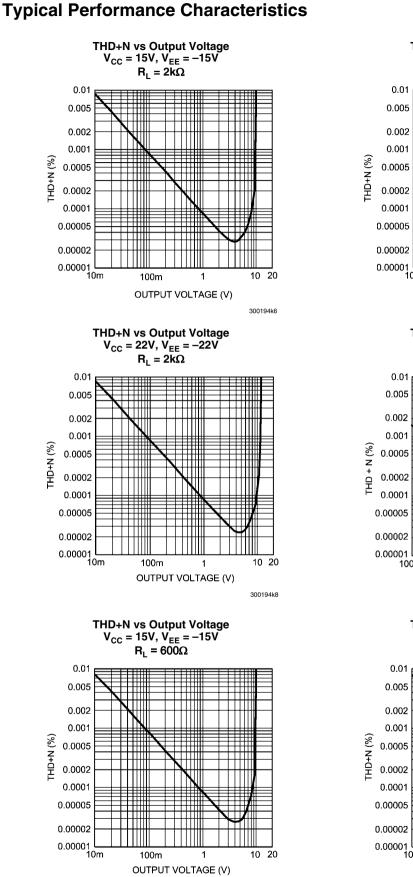
Note 4: Human body model, applicable std. JESD22-A114C. Note 5: Machine model, applicable std. JESD22-A115-A.

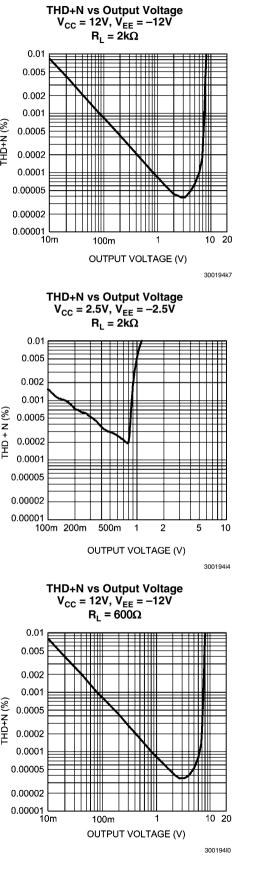
Note 6: Typical values represent most likely parametric norms at $T_A = +25^{\circ}C$, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.

Note 7: Datasheet min/max specification limits are guaranteed by test or statistical analysis.

Note 8: PSRR is measured as follows: For V_S, V_{OS} is measured at two supply voltages, \pm 7V and \pm 22V, PSRR = |20log(Δ V_{OS}/ Δ V_S)|.

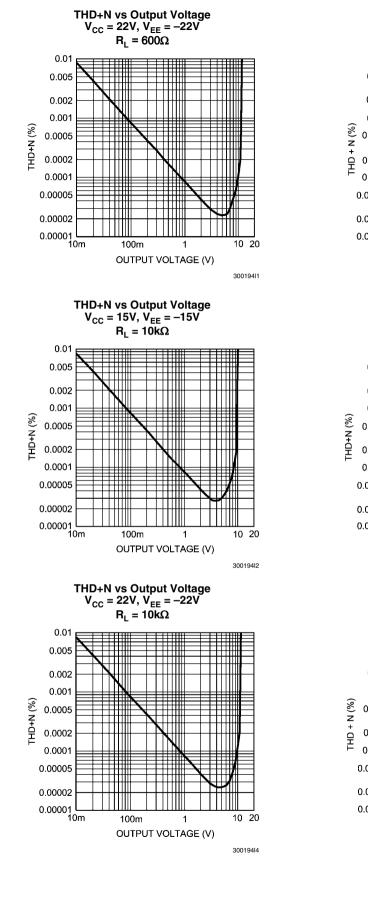


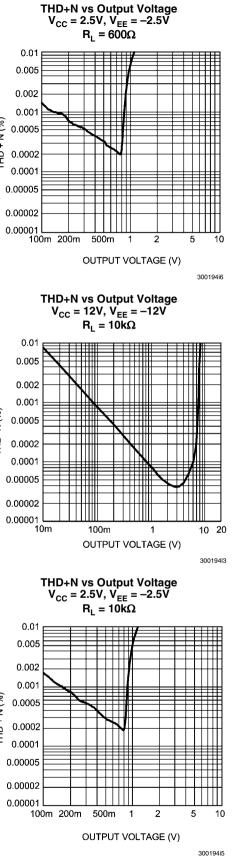


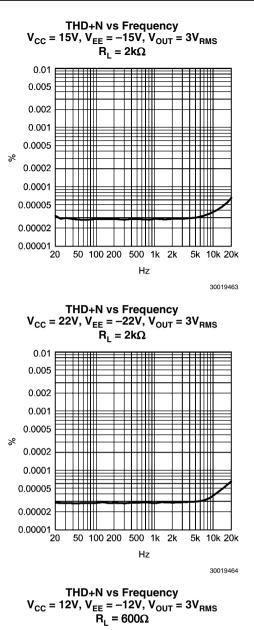


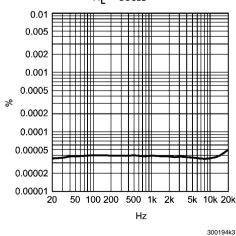
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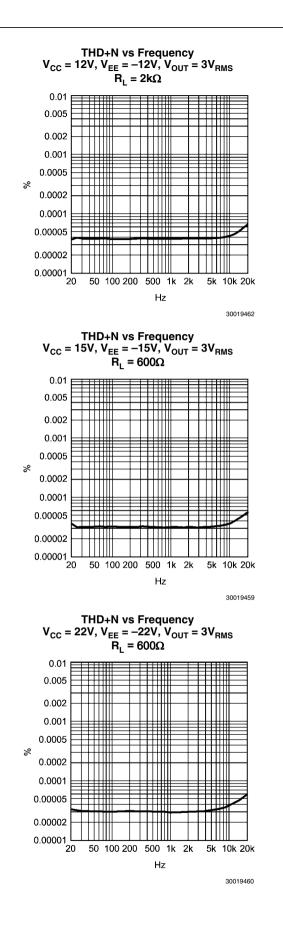




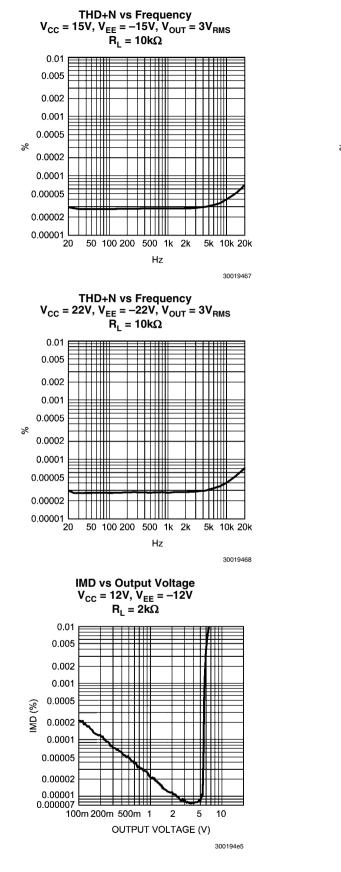


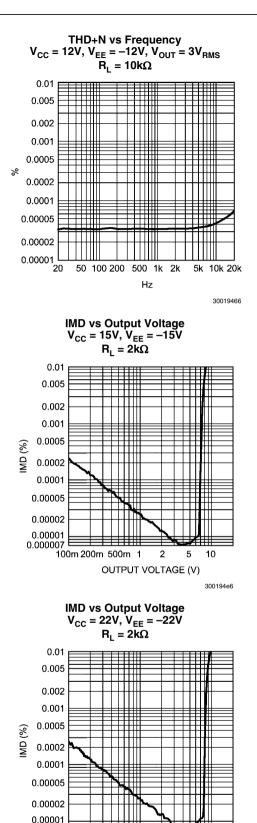












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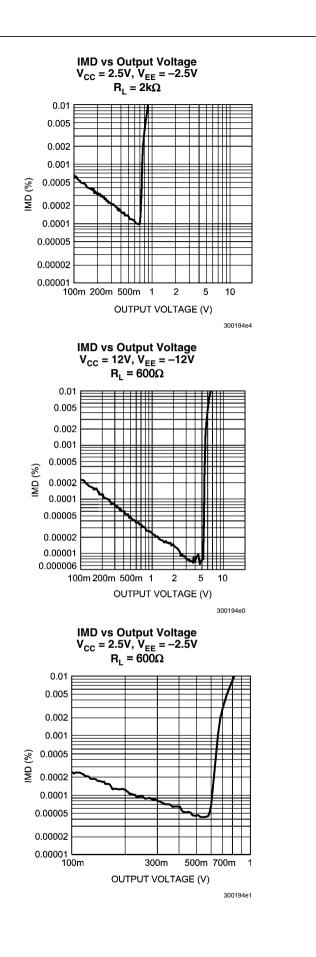
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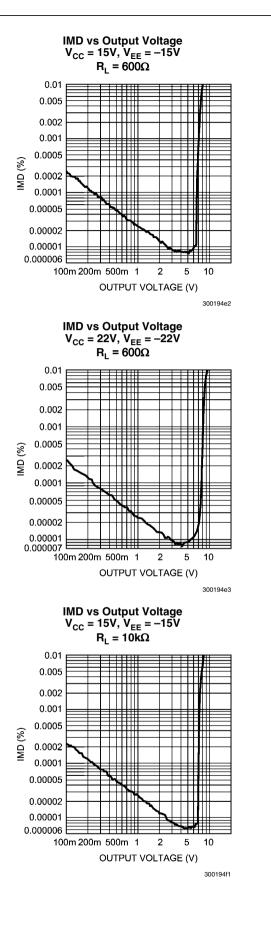
OUTPUT VOLTAGE (V)

0.000007

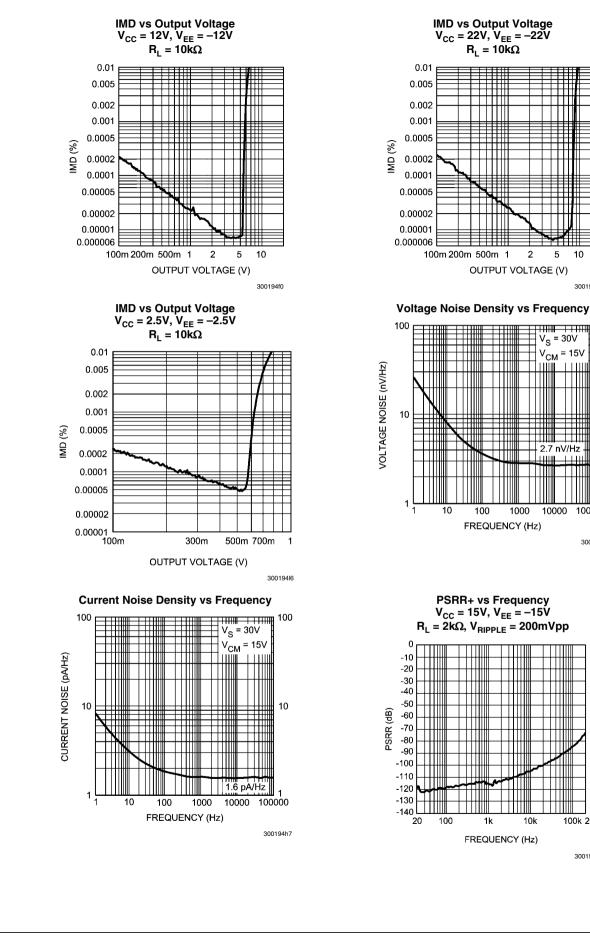
100m 200m 500m 1











2

10 5

100 III

V_S = 30V

V_{CM} = 15V

2.7 nV/Hz

10000

10k

100k 200k

300194p7

300194f2

10

100000

300194h6

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100k 200k

300194a0

1k

1k

10k

1k

10k

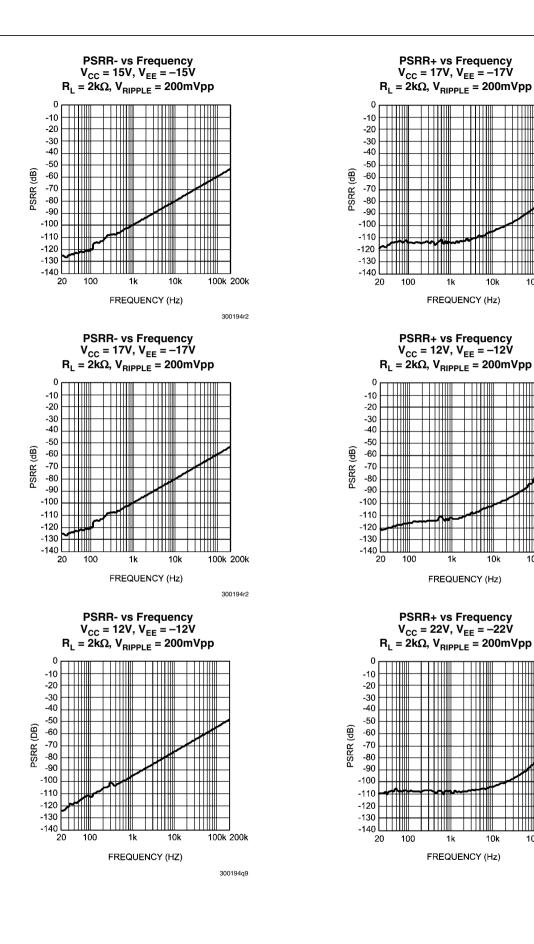
100k 200k

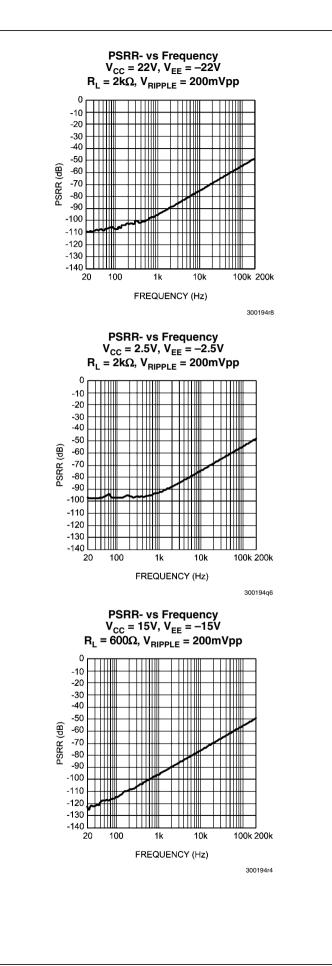
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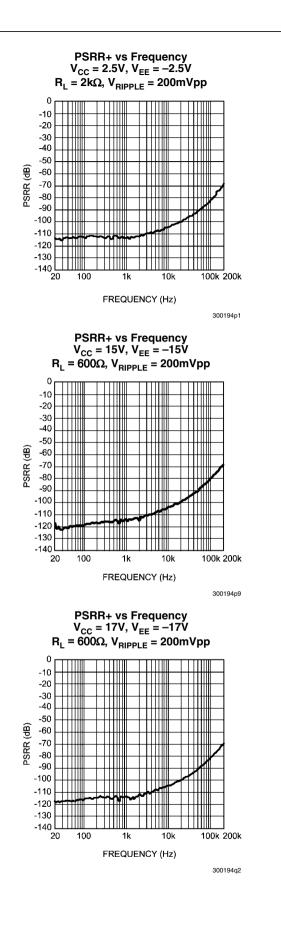
100k 200k

300194q3

10k







10k

1k FREQUENCY (Hz)

┤╢

1k

FREQUENCY (Hz)

10k

100k 200k

300194p6

100k 200k

300194q5

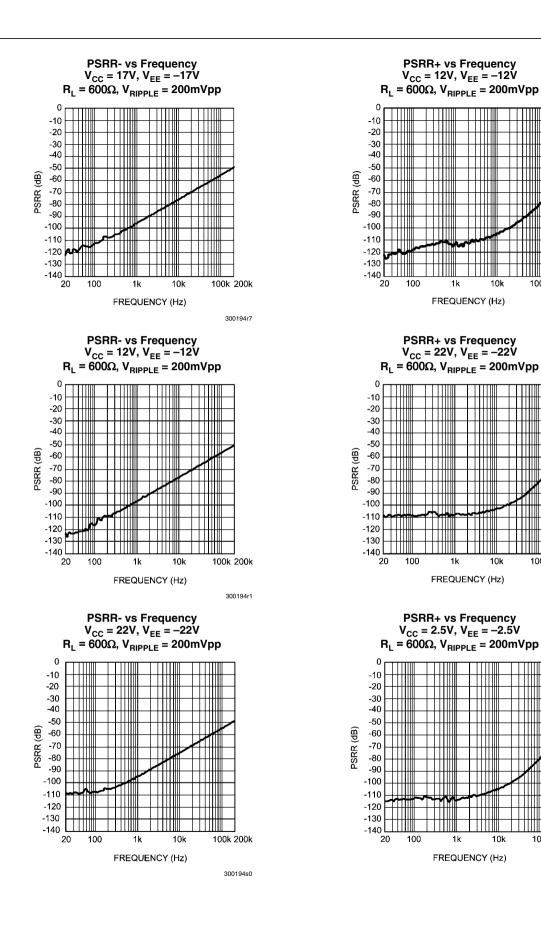
100k 200k

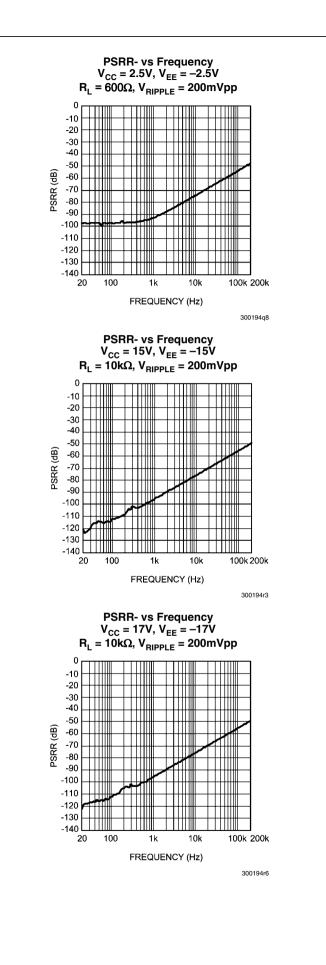
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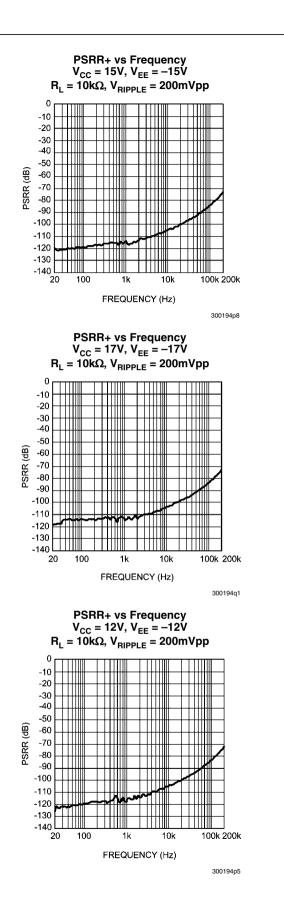
10k

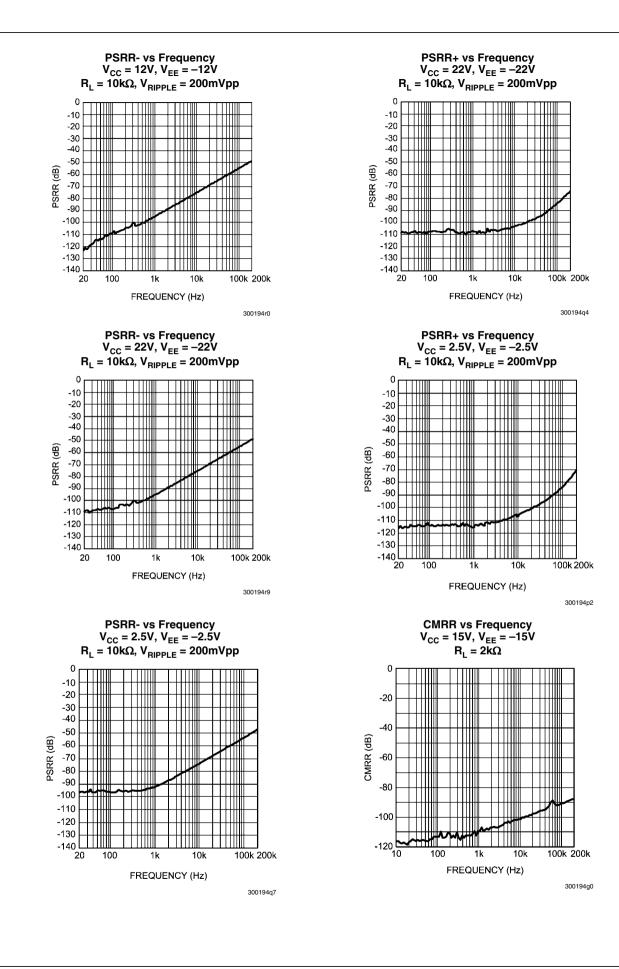
1k

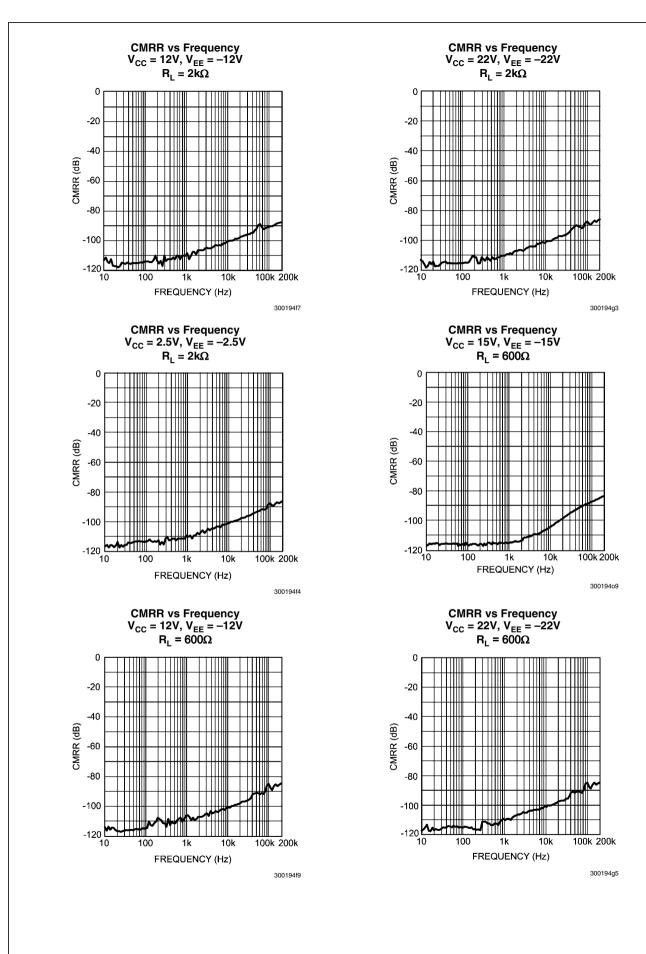
FREQUENCY (Hz)

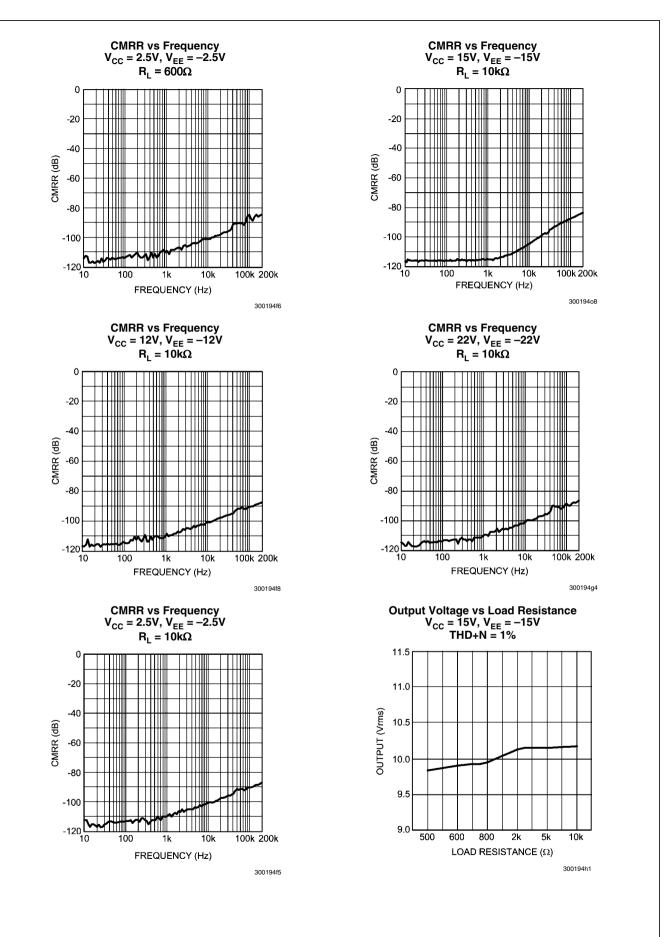




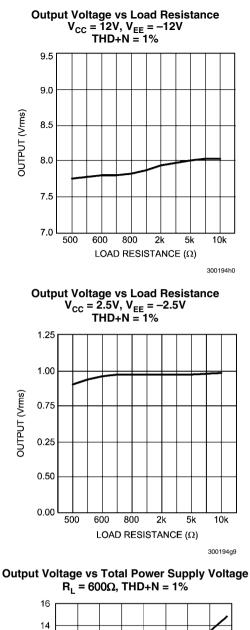


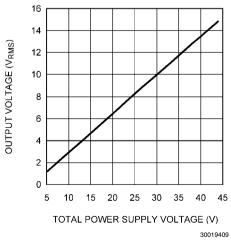


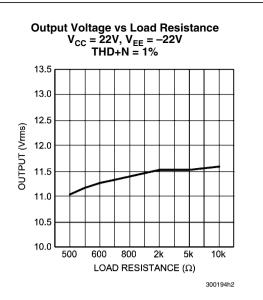




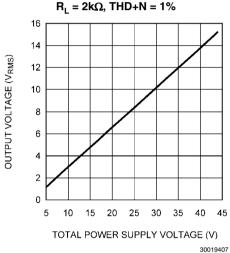




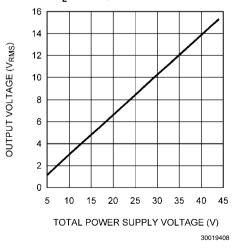




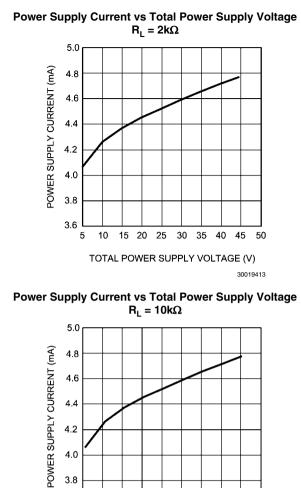
Output Voltage vs Total Power Supply Voltage $B_{1} = 2k_{0}$ THD: N = 1%

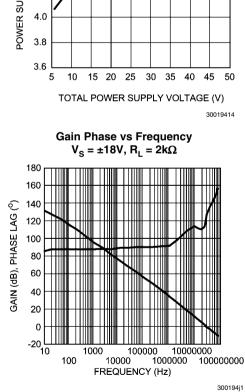


Output Voltage vs Total Power Supply Voltage $R_L = 10k\Omega$, THD+N = 1%









Power Supply Current vs Total Power Supply Voltage $R_1 = 600\Omega$ 5.0 POWER SUPPLY CURRENT (mA) 4.8 4.6 4.4 4.2 4.0 3.8 3.6 5 10 15 20 25 30 35 40 45 50 TOTAL POWER SUPPLY VOLTAGE (V) 30019415 **Full Power Bandwidth vs Frequency** $V_{S} = \pm 18V, R_{L} = 2k\Omega$ 2 0 -2 0 dB = 1 V P.P -4 MAGNITUDE (dB) -6 -8

-10 -12

-14

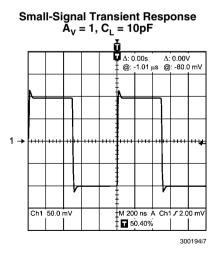
-16

-18

1

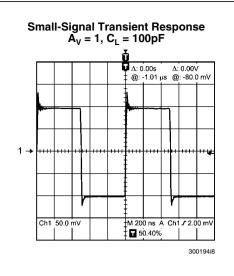
10 100 1k

FREQUENCY (Hz)



10k 100k 1M 10M 100M

300194i0



Application Information

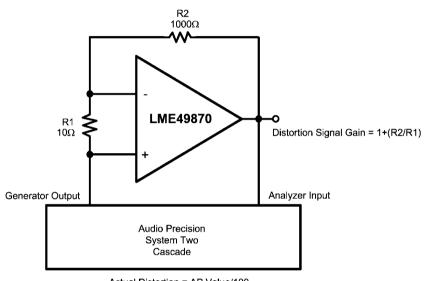
DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49870 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49870's low residual distortion is an input referred internal error. As shown in Figure 1, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting

inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 1.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



Actual Distortion = AP Value/100

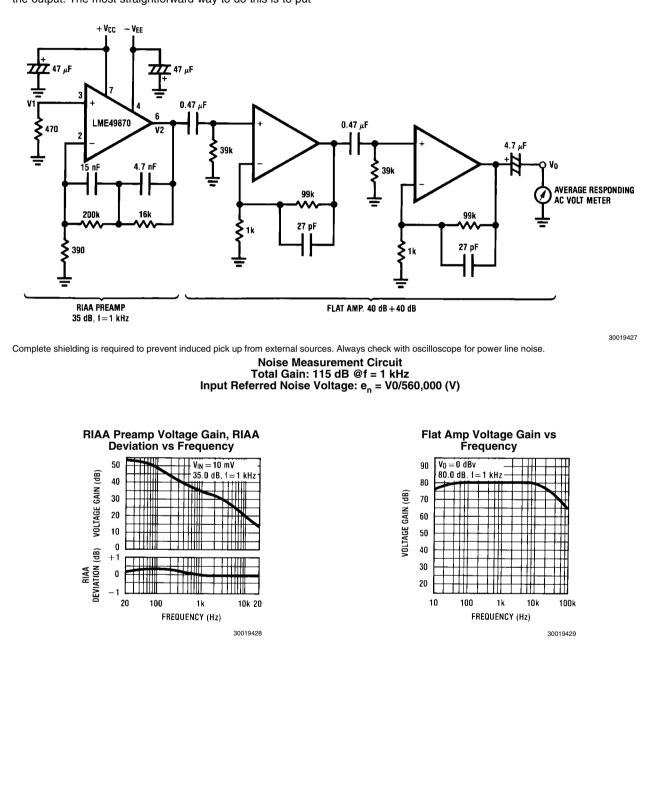
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FIGURE 1. THD+N and IMD Distortion Test Circuit

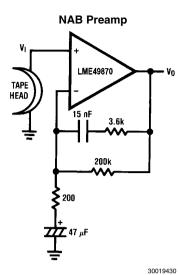
The LME49870 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

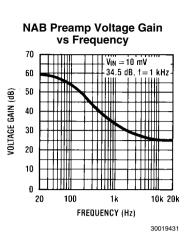
a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put



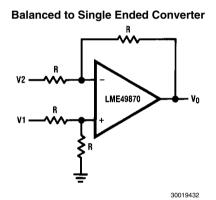
TYPICAL APPLICATIONS

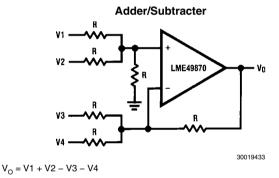




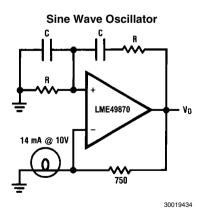
A_V = 34.5 F = 1 kHz E_n = 0.38 μV

A Weighted

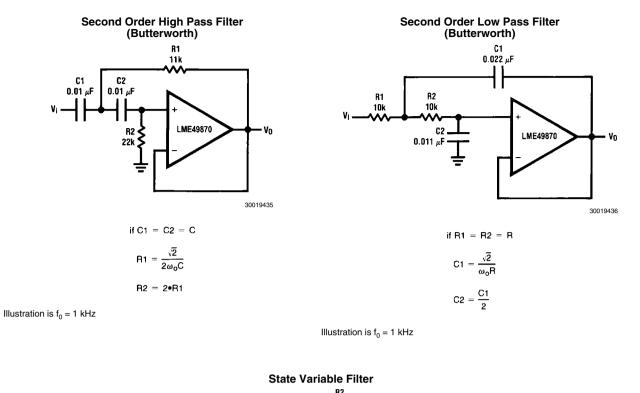




 $V_0 = V1 - V2$







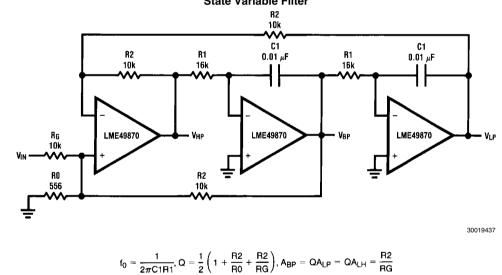
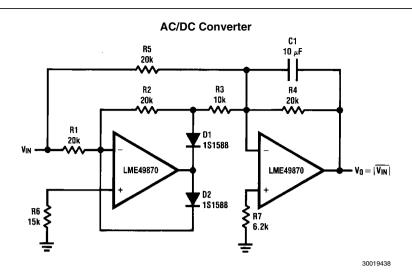
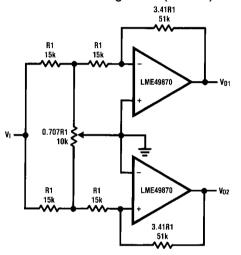


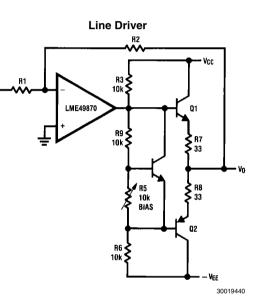
Illustration is $f_0 = 1$ kHz, Q = 10, A_{BP} = 1

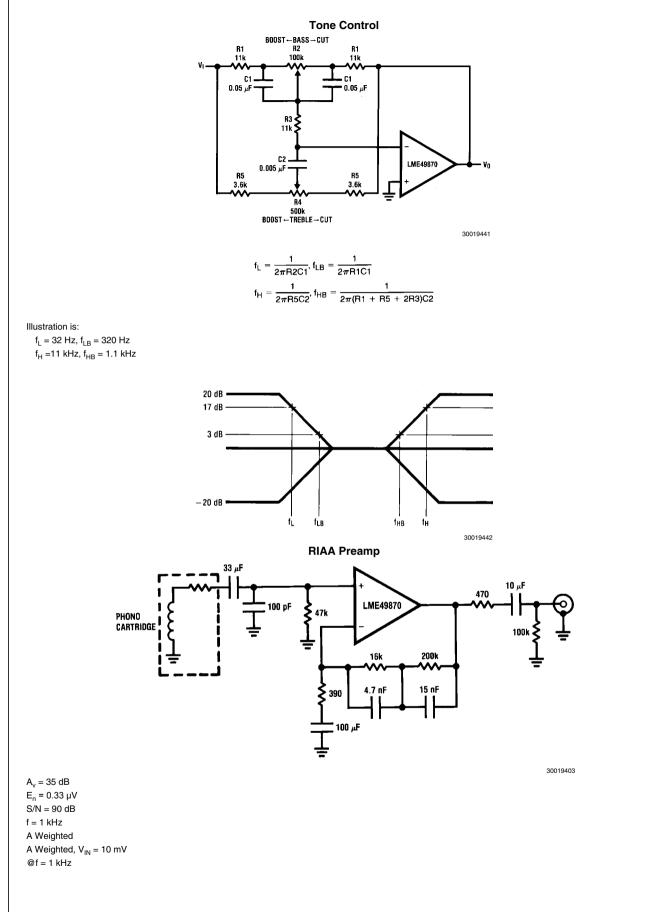


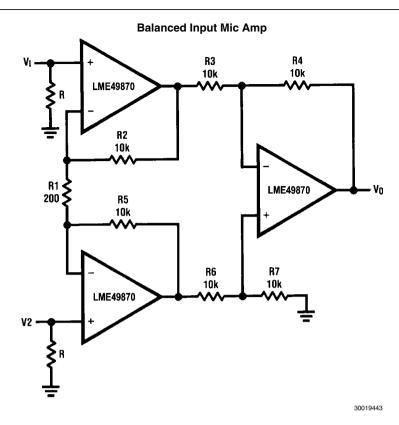
² Channel Panning Circuit (Pan Pot)





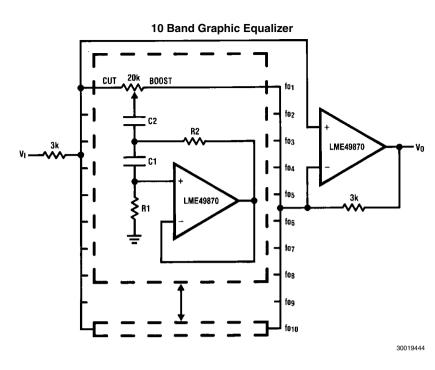






If R2 = R5, R3 = R6, R4 = R7 V0 = $\left(1 + \frac{2R2}{R1}\right)\frac{R4}{R3}(V2 - V1)$

Illustration is: V0 = 101(V2 - V1)

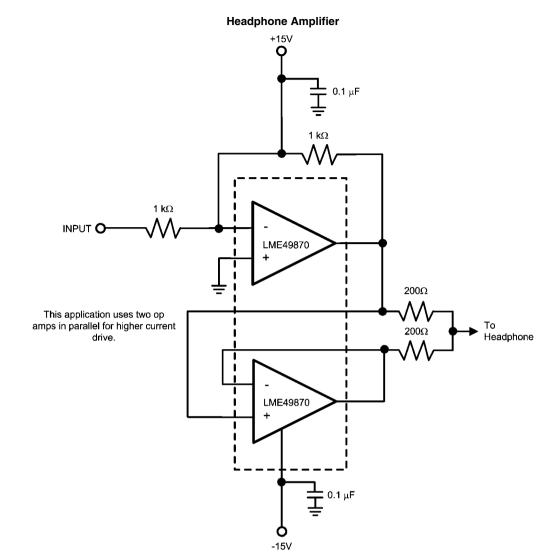


fo (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015µF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω

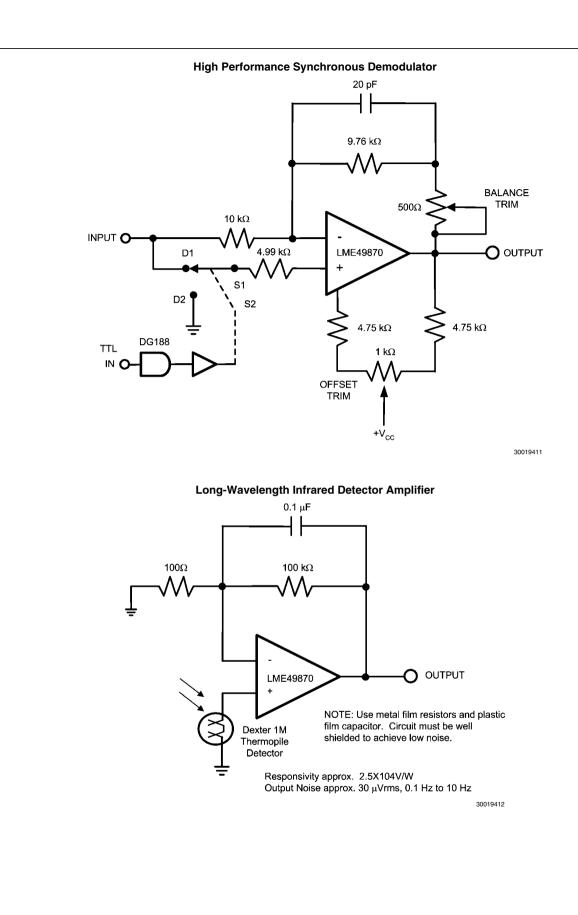
Note 9: At volume of change = $\pm 12 \text{ dB}$

Q = 1.7

Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2-61



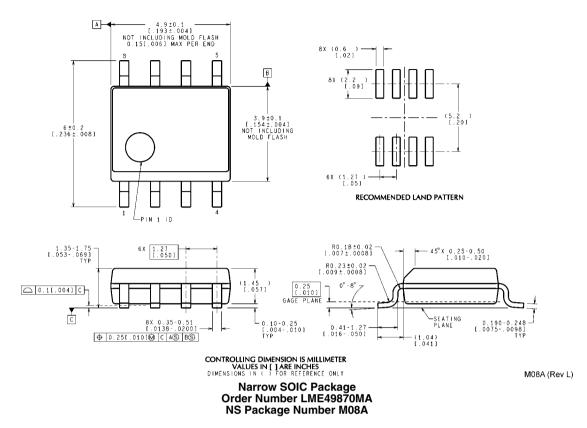
30019410



Revision History

Rev	Date	Description
1.0	1.0 09/20/07 Initial release.	
1.1	09/27/07 Updated Notes 1–7 (per National standard).	
1.2	12/20/07 Deleted all Crosstalk vs Frequency curves.	
1.3	01/14/08	Edited some graphics.

Physical Dimensions inches (millimeters) unless otherwise noted



Notes

Notes

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